Exhibit 8

U.S. Patent No. 7,803,423

"1. A method of producing nanoparticles comprising: effecting conversion of a nanoparticle precursor composition to a material of the nanoparticles,"

1. A method of producing nanoparticles comprising: effecting conversion of a nanoparticle precursor composition to a material of the nanoparticles,

eles The Samsung Q60R QLED TV is an exemplary LED TV (the "Samsung TV") that includes nanoparticles.



¹ Upon information and belief, all Samsung QLED TVs listed in Exhibit 6 include the same Quantum Dots. For example, Samsung QLED TV's display stack includes a Blue LED and layer of Quantum Dots in a Quantum Dot Layer.

See e.g., "Environmentally Friendly Quantum Dots for Display Applications," Eunjoo Jang (SAIT, Samsung Electronics), Quantum Dot Forum 2018 Presentation (Exhibit 12) at Slides 11, 16.

see also e.g., https://www.techradar.com/news/samsung-qled-samsungs-latest-television-acronym-explained;

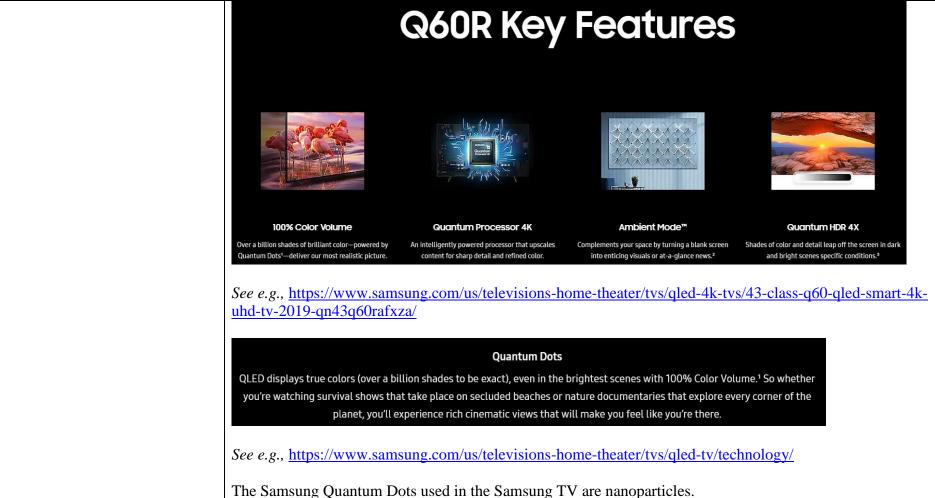
see also e.g., https://www.samsung.com/global/tv/blog/stained-glass-and-quantum-dot-technology/;

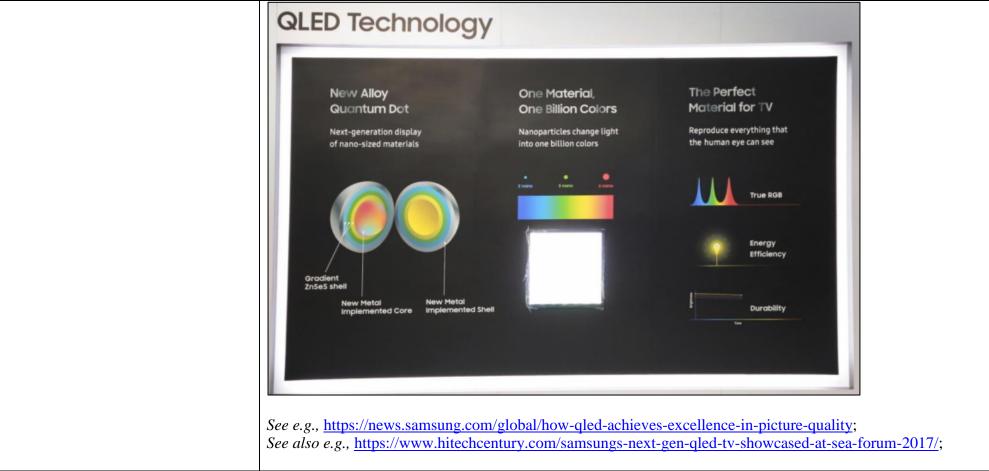
see also e.g., https://www.displaydaily.com/article/display-daily/future-of-quantum-dot-display-niche-or-mainstream;

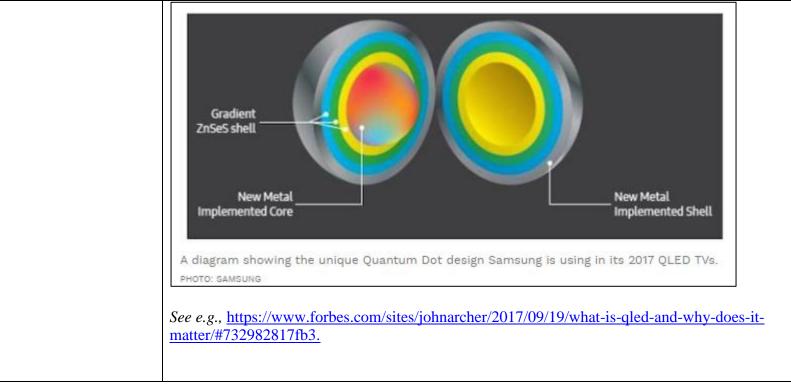
see also e.g., https://www.techradar.com/news/samsung-qled-samsungs-latest-television-acronym-explained.

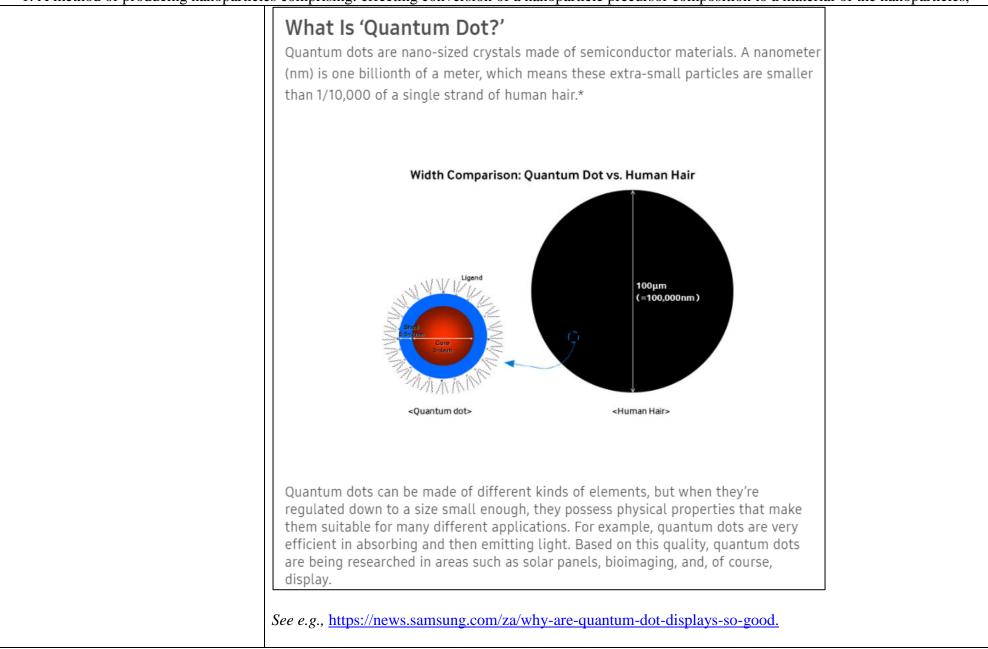
Samsung's QD-OLED TV displays operate in substantially the same way in that they are comprised of a Blue OLED and Quantum Dot layer.

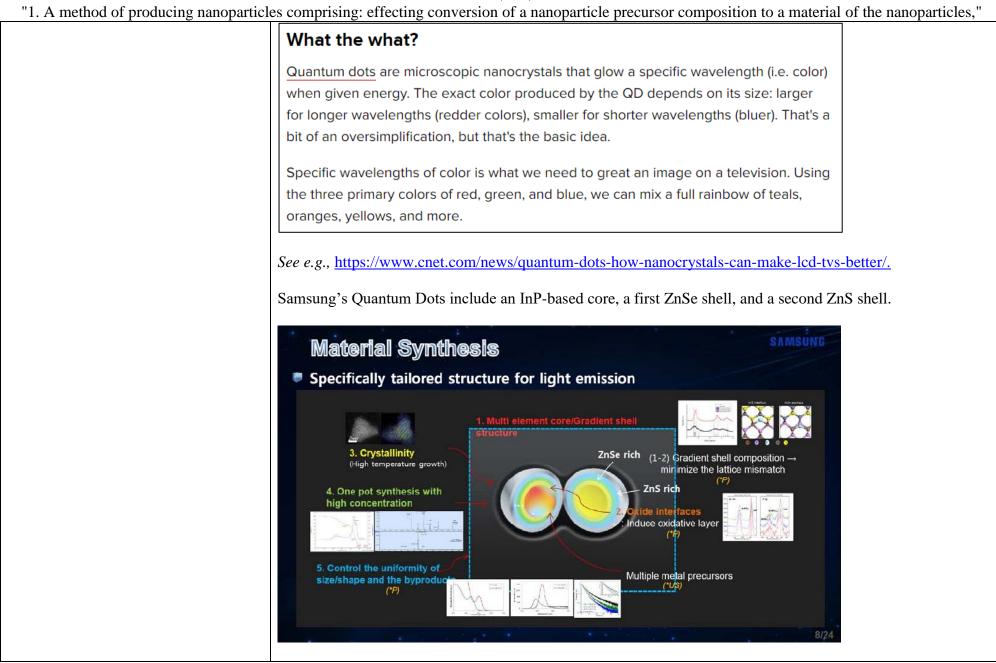
See e.g., https://www.cnet.com/news/samsung-reportedly-working-on-quantum-dot-oled-tv-hybrid/.

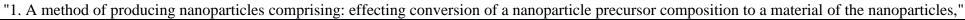


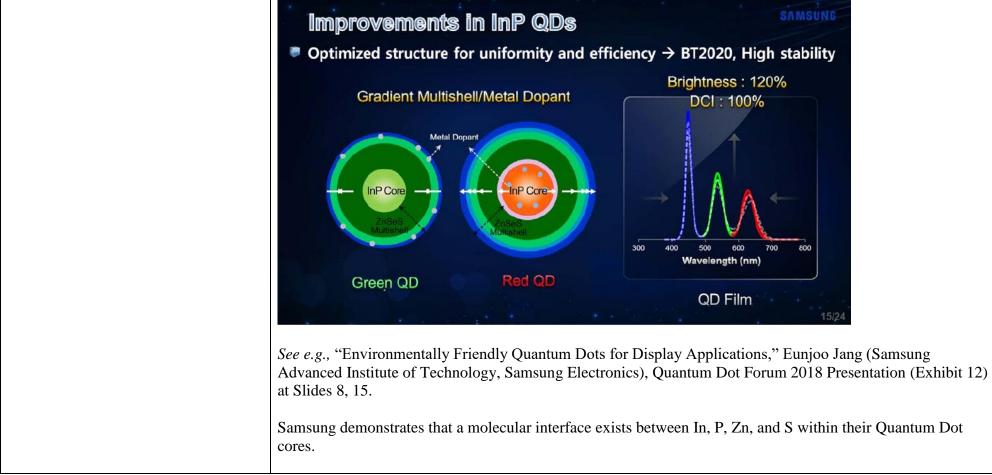


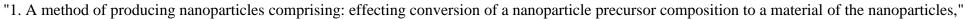


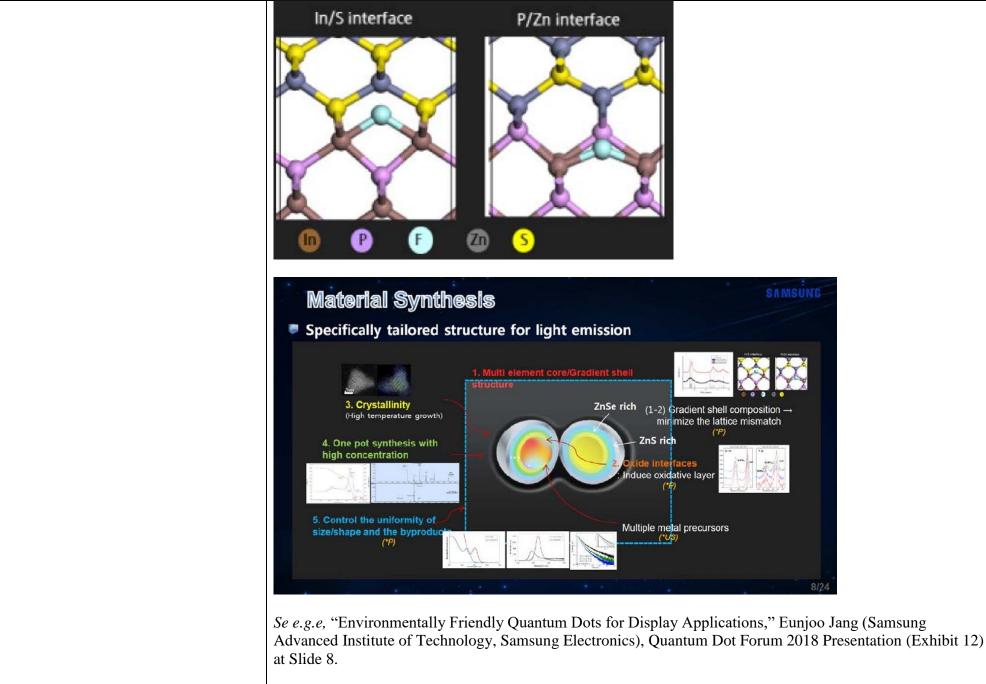


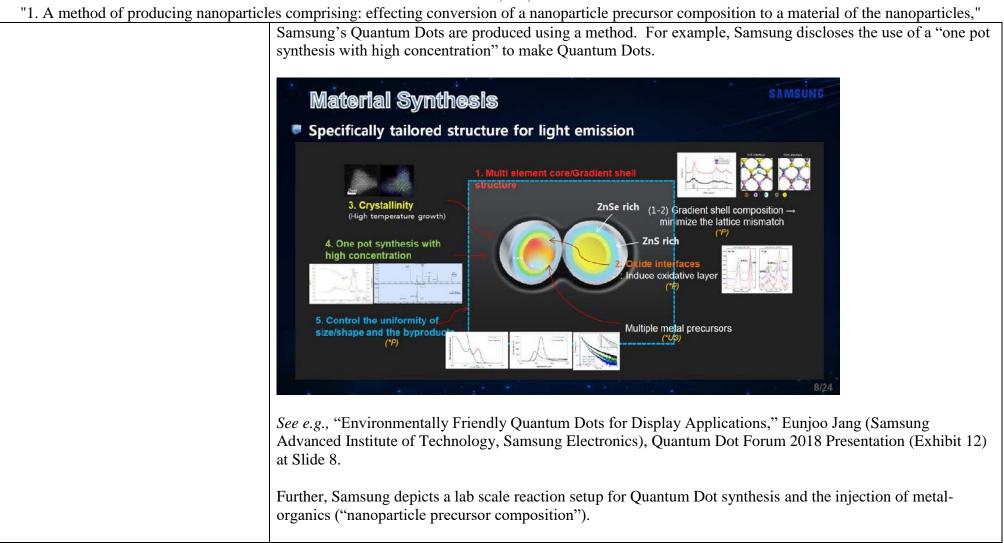


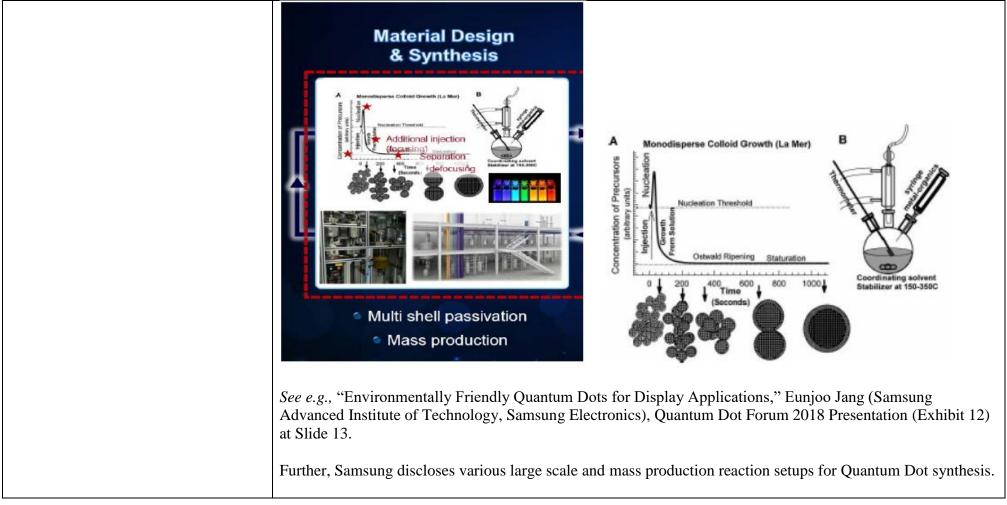


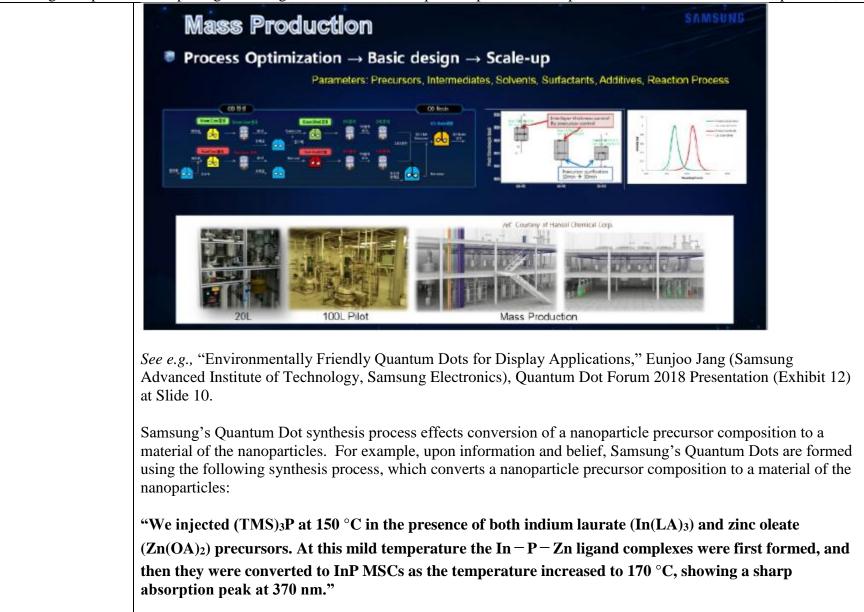


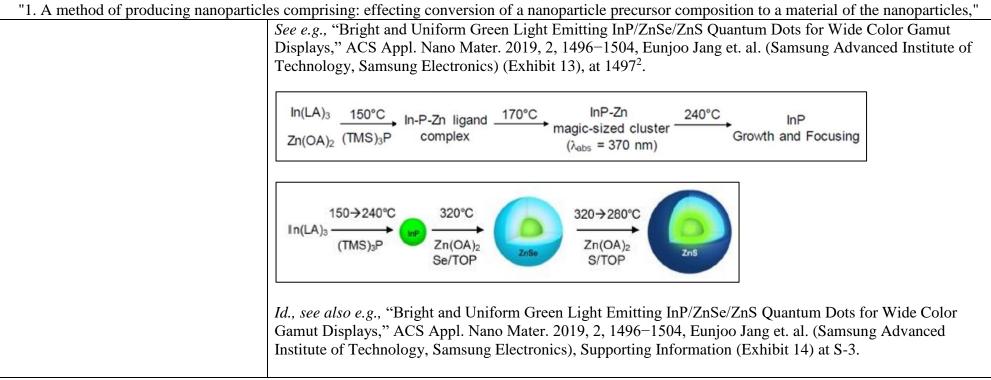












² Dr. Eunjoo Jang of Samsung's Advanced Institute of Technology (SAIT) is responsible for the synthesis of Samsung's Quantum Dots. *See e.g.*, <u>https://news.samsung.com/global/quantum-dot-artisan-dr-eunjoo-jang-samsung-fellow.</u> SAIT is Samsung's Research and Development Center. *See e.g.*, <u>https://www.sait.samsung.co.kr/saithome/mobile/research/what.do</u>. The cited paper—authored by Eunjoo Jang—describes a method for synthesizing InP/ZnSe/ZnS quantum dots. As previously shown, Samsung describes its quantum dots as comprising a core-shell structure of InP/ZnSe/ZnS. *See e.g.*, "Environmentally Friendly Quantum Dots for Display Applications," Eunjoo Jang (Samsung Advanced Institute of Technology, Samsung Electronics), Quantum Dot Forum 2018 Presentation (Exhibit 12) at Slides 8.

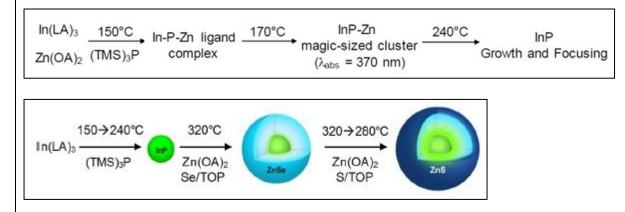
"said precursor composition comprising a first precursor species containing a first ion to be incorporated into the nanoparticles and a separate second precursor species containing a second ion to be incorporated into the nanoparticles,"

said precursor composition comprising a first precursor species containing a first ion to be incorporated into the nanoparticles and a separate second precursor species containing a second ion to be incorporated into the nanoparticles, The method used to synthesize the Samsung Quantum Dots uses a precursor composition comprising a first precursor species containing a first ion to be incorporated into the nanoparticles and a separate second precursor species containing a second ion to be incorporated into the nanoparticles.

Samsung's Quantum Dot synthesis process effects conversion of a nanoparticle precursor composition to a material of the nanoparticles. For example, upon information and belief, Samsung's Quantum Dots are formed using the following synthesis process, which converts a nanoparticle precursor composition to a material of the nanoparticles:

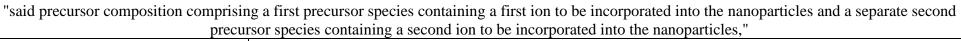
"We injected $(TMS)_3P$ at 150 °C in the presence of both indium laurate $(In(LA)_3)$ and zinc oleate $(Zn(OA)_2)$ precursors. At this mild temperature the In – P – Zn ligand complexes were first formed, and then they were converted to InP MSCs as the temperature increased to 170 °C, showing a sharp absorption peak at 370 nm."

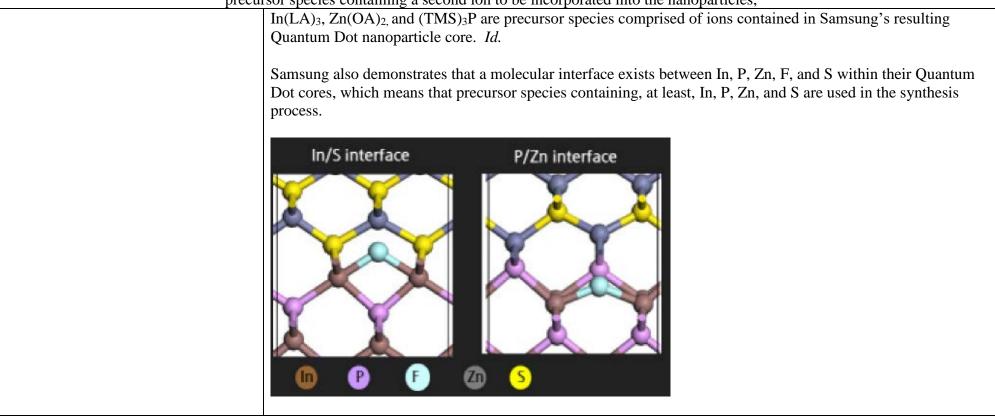
See e.g., "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics) (Exhibit 13), at 1497.



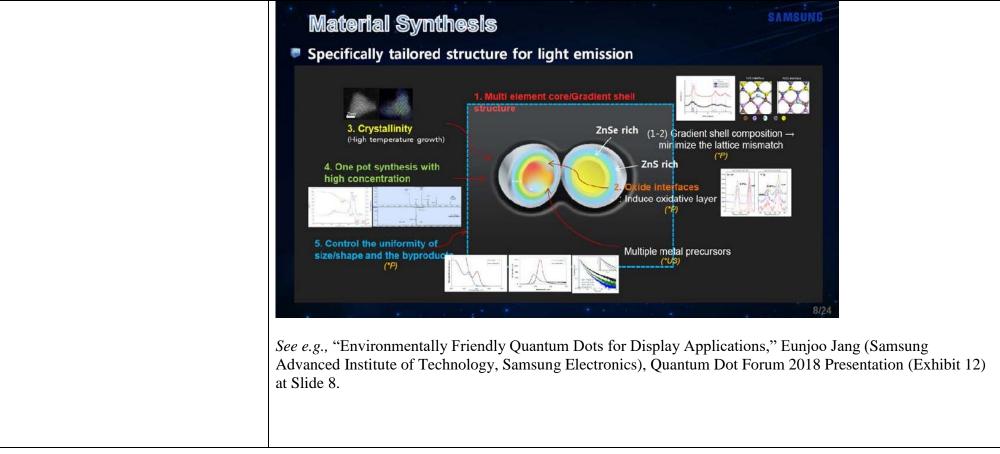
Id., see also e.g., "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics), Supporting Information (Exhibit 14) at S-3.

The precursor composition comprises a fist precursor specific containing a first ion to be incorporated into the nanoparticles and a separate second precursor species containing a second ion to be incorporated into the nanoparticles. For example, Samsung's Quantum Dot synthesis process demonstrates that, at least, two of





"said precursor composition comprising a first precursor species containing a first ion to be incorporated into the nanoparticles and a separate second precursor species containing a second ion to be incorporated into the nanoparticles,"



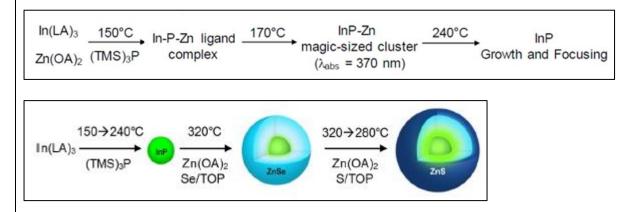
"wherein said conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles."

wherein said conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles. The conversion in the method used to synthesize the Samsung Quantum Dots is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles.

For example, Samsung's Quantum Dots are formed using the following synthesis process, which converts a nanoparticle precursor composition to a material of the nanoparticles:

"We injected (TMS)₃P at 150 °C in the presence of both indium laurate (In(LA)₃) and zinc oleate (Zn(OA)₂) precursors. At this mild temperature the In -P-Zn ligand complexes were first formed, and then they were converted to InP MSCs as the temperature increased to 170 °C, showing a sharp absorption peak at 370 nm."

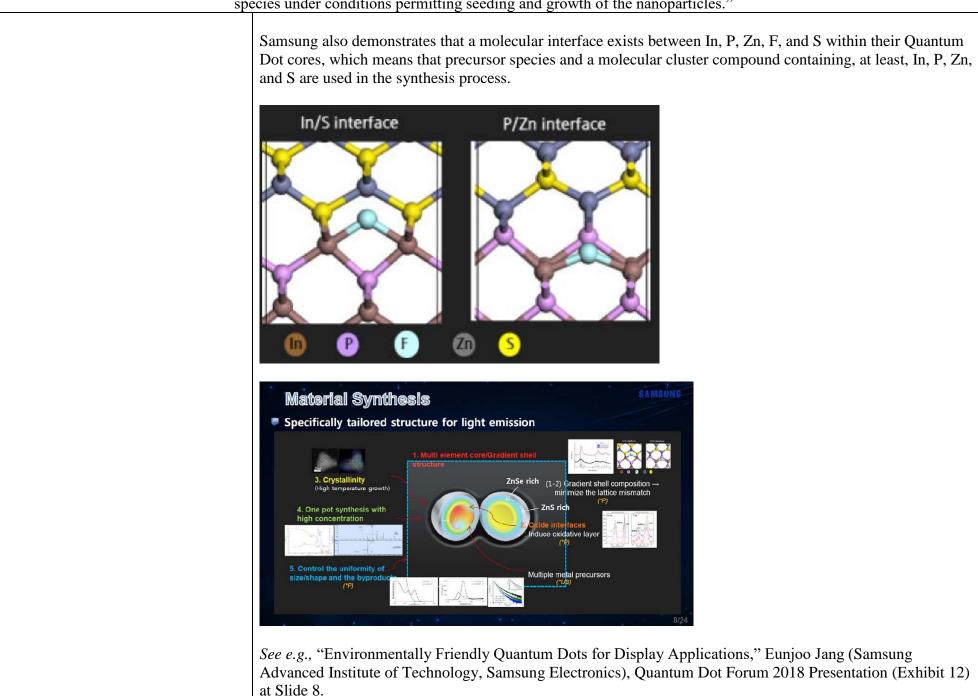
See e.g., "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics) (Exhibit 13), at 1497.



Id., see also e.g., "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics), Supporting Information (Exhibit 14) at S-3.

The conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles. For example, Samsung's Quantum Dot synthesis process demonstrates that, at least, In(LA)₃, Zn(OA)₂, and (TMS)₃P are precursor species and a molecular cluster compound that are all different from each other and comprised of ions contained in Samsung's resulting Quantum Dot nanoparticle core. *Id*.

"wherein said conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles."



"wherein said conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles."

species under conditions permitting seeding and growth of the nanoparticles."	
	The conversion is effected under conditions permitting seeding and growth of nanoparticles. For example, Samsung's Quantum Dots are formed using the following synthesis process:
	"During the InP synthesis, unlike the LaMer type growth, it has been known that the initial nucleation phase completely consumes the highly reactive P precursor such as (TMS)3P, and further growth takes place through the Ostwald ripening, which results in a large size distribution."
	"We injected (TMS)3P at 150 °C in the presence of both indium laurate (In(LA)3) and zinc oleate
	(Zn(OA)2) precursors. At this mild temperature the In $-P-Zn$ ligand complexes were first formed, and
	then they were converted to InP MSCs as the temperature increased to 170 °C, showing a sharp absorption peak at 370 nm."
	See e.g., "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics) (Exhibit 13), at 1497.
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	<i>Id., see also e.g.,</i> "Bright and Uniform Green Light Emitting InP/ZnSe/ZnS Quantum Dots for Wide Color Gamut Displays," ACS Appl. Nano Mater. 2019, 2, 1496–1504, Eunjoo Jang et. al. (Samsung Advanced Institute of Technology, Samsung Electronics), Supporting Information (Exhibit 14) at S-3.
	Further, Samsung discloses its material design and synthesis process which permits seeding and growth of nanoparticles.

"wherein said conversion is effected in the presence of a molecular cluster compound different from the first precursor species and the second precursor species under conditions permitting seeding and growth of the nanoparticles."

